

**Product data sheet** 

# 1. Product profile

## 1.1 General description

PNP transistor in a SOT323 (SC-70) plastic package. The NPN complement is 2PC4081.

#### 1.2 Features

- Low current (max. 150 mA)
- Low voltage (max. 50 V)
- Low collector capacitance (typ. 2.5 pF)

#### 1.3 Applications

General-purpose switching and amplification

# 2. Pinning information

Table 1. **Pinning** 

	3	
Pin	Description	Simplified outline Symbol
1	base	
2	emitter	3
3	collector	1 1 2 2
		sym013

#### **Ordering information** 3.

**Ordering information** Table 2.

Type number	Package	Package				
	Name	Description	Version			
2PA1576Q	SC-70	plastic surface mounted package; 3 leads	SOT323			
2PA1576R						
2PA1576S						



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#### PNP general-purpose transistor

## **Marking**

Table 3. **Marking codes** 

Type number	Marking code <sup>[1]</sup>
2PA1576Q	F*Q
2PA1576R	F*R
2PA1576S	F*S

<sup>[1] \* = -:</sup> made in Hong Kong

#### **5**. **Limiting values**

Table 4. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •			
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{CBO}}$	collector-base voltage	open emitter	-	-60	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current (DC)		-	-150	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[1] -	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

#### **Thermal characteristics** 6.

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> -	-	625	K/W

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

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<sup>\* =</sup> t: made in Malaysia

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## **Characteristics**

Table 6. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

	_					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V}$	-	-	-100	nΑ
		$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V};$ $T_j = 150 \text{ °C}$	-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$I_C = 0 A; V_{EB} = -4 V$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -6 \text{ V}$				
	2PA1576Q		120	-	270	
	2PA1576R		180	-	390	
	2PA1576S		270	-	560	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -50 \text{ mA};$ $I_B = -5 \text{ mA}$	[1] -	-	-500	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A};$ $V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$	-	2.5	3.5	pF
f <sub>T</sub>	transition frequency	$I_C = -2 \text{ mA};$ $V_{CE} = -12 \text{ V};$ f = 100  MHz	100	-	-	MHz

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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# Package outline

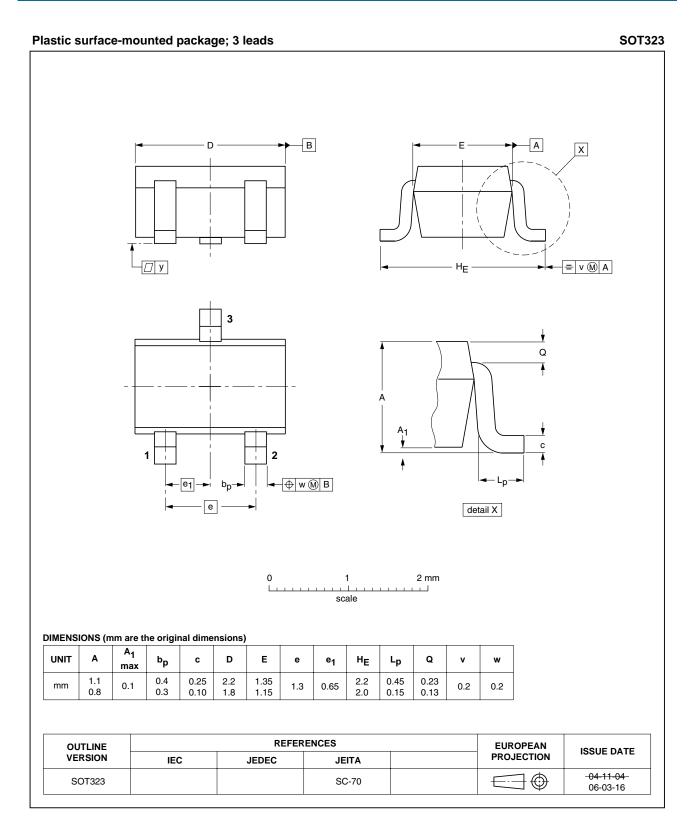


Fig 1. Package outline SOT323 (SC-70)

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# 9. Revision history

## Table 7. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes
2PA1576_6	20091117	Product data sheet	-	2PA1576_5
Modifications:	including net content.	eet was changed to reflect t w legal definitions and discla ckage outline SOT323 (SC-	aimers. No changes w	
2PA1576_5	20041124	Product data sheet	-	2PA1576_4
2PA1576_4	19990531	Product specification	-	2PA1576_3
2PA1576_3	19970328	Objective specification	-	2PA1576_2
2PA1576_2	19931213	n.a.	-	n.a.

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#### Data sheet status 10.1

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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